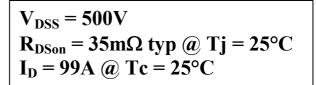
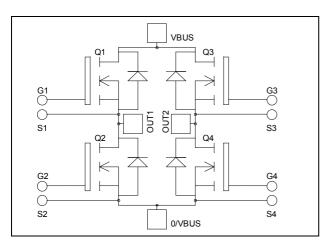


Full - Bridge MOSFET Power Module





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Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		500	V
I_{D}	Continuous Drain Current	$T_c = 25$ °C	99	
ъ	Continuous Diani Current	$T_c = 80$ °C	74	A
I_{DM}	Pulsed Drain current		396	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		39	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	781	W
I_{AR}	Avalanche current (repetitive and non repetitive)		51	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy	·	3000	1113

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 500V$	$\Gamma_{\rm j} = 25^{\circ}{\rm C}$			200	۸	
		$V_{GS} = 0V, V_{DS} = 400V \qquad T$	$\Gamma_{\rm j} = 125^{\circ}{\rm C}$			1000	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 49.5A$			35	39	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		3		5	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{V}$		·		±150	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Ciss	Input Capacitance	$V_{GS} = 0V$		14		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		2.8		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.2		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		280		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 250V$		80		nC
$Q_{gd} \\$	Gate – Drain Charge	$I_D = 99A$		140		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		21		ns
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		38		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 333V$ $I_{\text{D}} = 99A$		75		
T_{f}	Fall Time	$R_G = 1\Omega$		93		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 99A, R_G = 1\Omega$		2070		1
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			1690		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		3112		т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 99A, R_G = 1\Omega$		2026		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			99	Α
	(Body diode)		$Tc = 80^{\circ}C$			74	А
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -99A$	L			1.3	V
dv/dt	Peak Diode Recovery					15	V/ns
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$			270	ns
	reverse receivery Time	$I_S = -99A$ $V_R = 333V$	$T_j = 125$ °C			540	115
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		5.2		μC
			$T_j = 125$ °C		19.2		

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

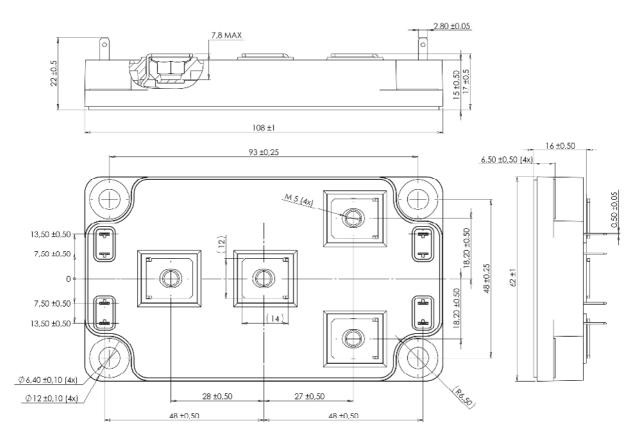
 $I_S \leq \text{--} 99A \qquad \text{di/dt} \leq 700 \text{A/} \mu \text{s} \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} \text{C}$



Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.16	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range -40 Storage Temperature Range -40 Operating Case Temperature -40					150	
T_{STG}						125	°C
$T_{\rm C}$						100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

SP6 Package outline (dimensions in mm)

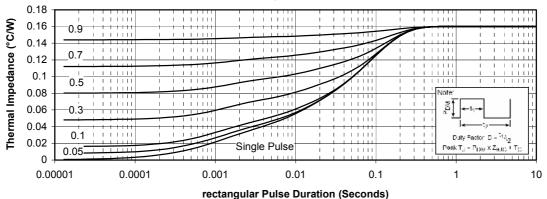


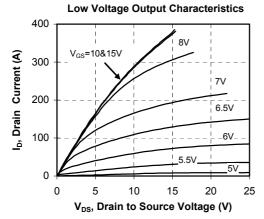
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



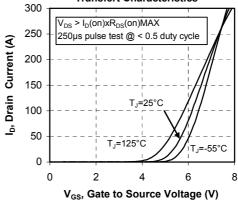
Typical Performance Curve

Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration

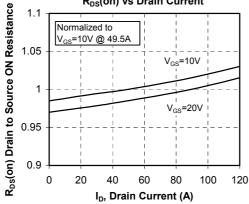




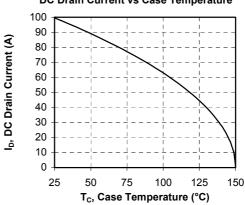
Transfert Characteristics



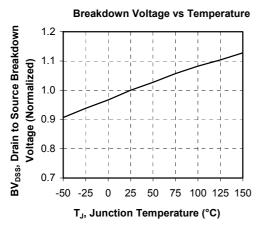
R_{DS}(on) vs Drain Current 1.1

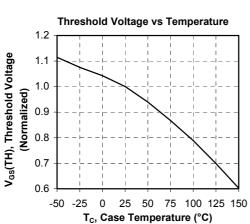


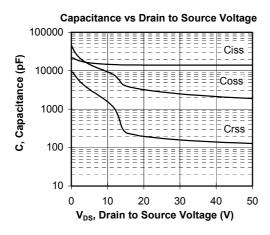
DC Drain Current vs Case Temperature

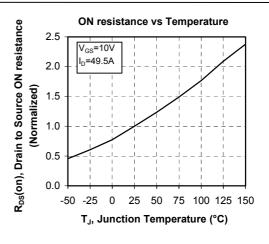


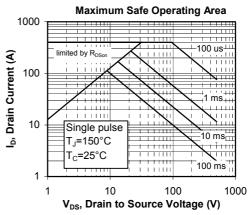


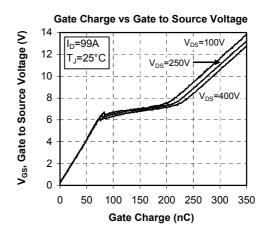




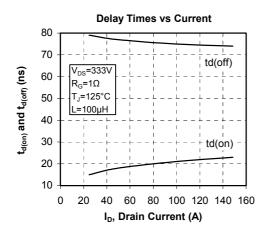


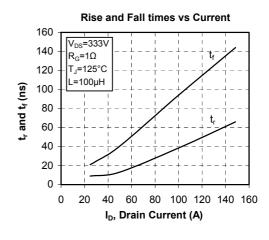


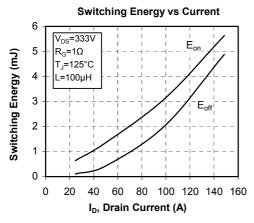


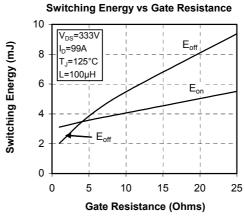


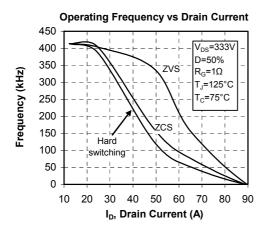


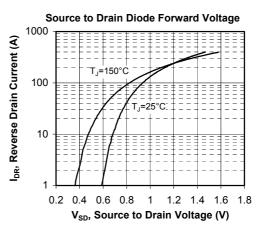














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